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ST30100C STB30100C STF30100C

Technical Data Data Sheet N1047, Rev. C



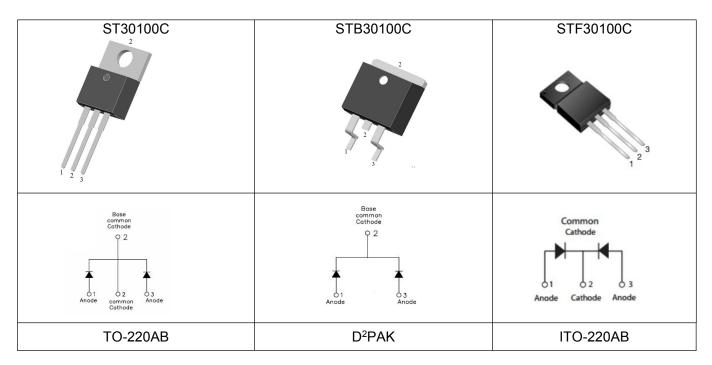
ST30100C/STB30100C/STF30100C SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 150 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	15(Per Leg) 30(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	200	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, TJ = 25 °C @ 7.5A, Pulse, TJ = 25 °C @ 15A, Pulse, TJ = 25 °C	0.50 0.61 0.70	- - 0.75	V
	V _{F2}	@ 5A, Pulse, TJ = 125 °C @ 7.5A, Pulse, TJ = 125 °C @ 15A, Pulse, TJ = 125 °C	0.46 0.53 0.66	- - 0.68	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.023	0.5	mA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	3.19	55	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	686	-	pF

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

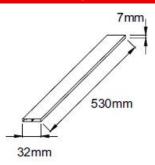
Characteristics	Symbol	ST30100C	STB30100C	STF30100C	Units
Junction Temperature	TJ		-55 to +150		°C
Storage Temperature	T _{stg}	-55 to +150			°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	2.8	2.8	5.5	°C/W

Tube Specification

Device	Package	Weight	Shipping
ST30100C	TO-220AB	2.0	50pcs / tube
STB30100C	D ² PAK	1.85	800pcs / reel
STF30100C	ITO-220AB	2.0	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB/ITO-220AB)

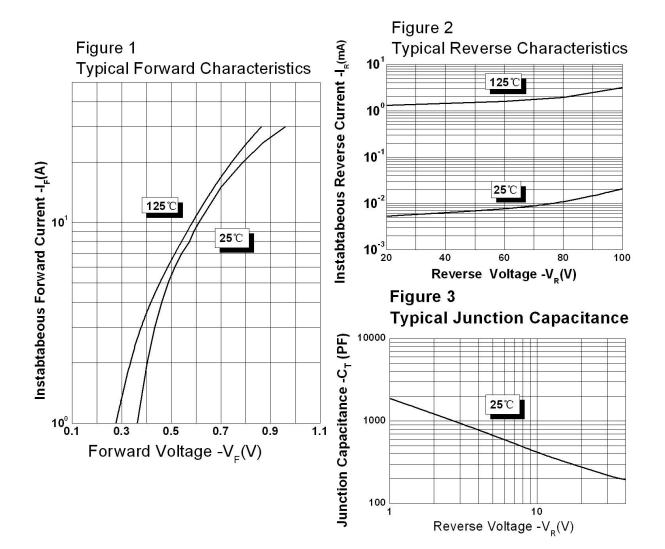




ST30100C STB30100C STF30100C



Ratings and Characteristics Curves



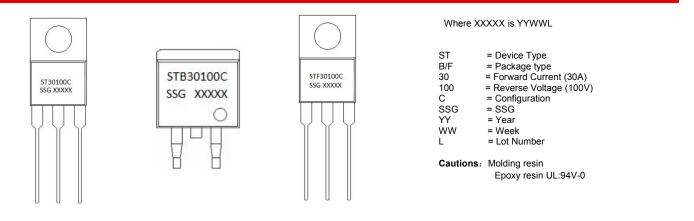


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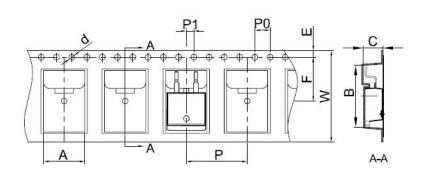
Technical Data Data Sheet N1047, Rev. C

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Marking Diagram



Carrier Tape Specification D2PAK



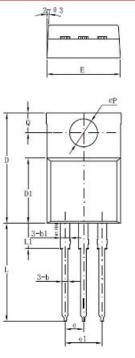
SYMBOL	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

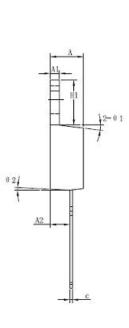


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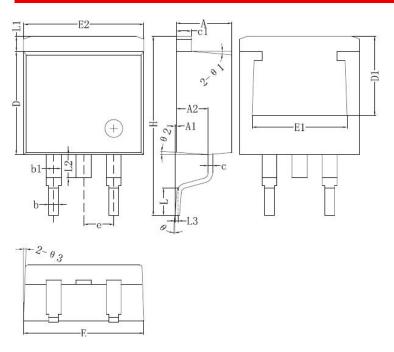
Mechanical Dimensions TO-220AB





Symbol	Dimensions in millimeters			
	Min	Typical	Max	
A	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7 °		
Θ2		3°		
Θ3		4°		

Mechanical Dimensions D²PAK



	Dimensions in millimeters				
Symbol	Min.	Typical	Max.		
A	4.55	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.55	8.70	8.85		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.18		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.70		
L1	1.17	1.27	1.40		
L2			2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

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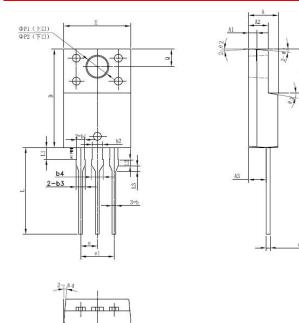
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Mechanical Dimensions ITO-220AB



	Dimensions in millimeters			
Symbol	Min.	Typical	Max.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦΡ1(上口)	3.30	3.50	3.70	
ΦP2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

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